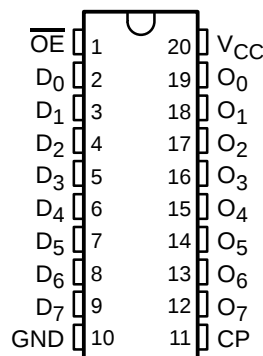


CY54FCT574T, CY74FCT574T 8-BIT REGISTERS WITH 3-STATE OUTPUTS

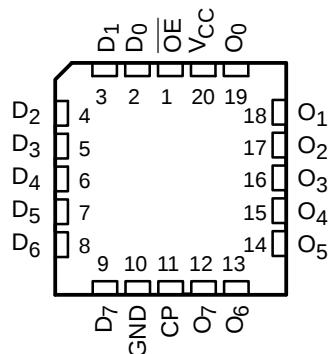
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- Function, Pinout, and Drive Compatible With FCT and F Logic
- Reduced V_{OH} (Typically = 3.3 V) Versions of Equivalent FCT Functions
- Edge-Rate Control Circuitry for Significantly Improved Noise Characteristics
- I_{off} Supports Partial-Power-Down Mode Operation
- Matched Rise and Fall Times
- Fully Compatible With TTL Input and Output Logic Levels
- ESD Protection Exceeds JESD 22
 - 2000-V Human-Body Model (A114-A)
 - 200-V Machine Model (A115-A)
 - 1000-V Charged-Device Model (C101)
- Edge-Triggered D-Type Inputs
- 250-MHz Typical Switching Rate
- CY54FCT574T
 - 32-mA Output Sink Current
 - 12-mA Output Source Current
- CY74FCT574T
 - 64-mA Output Sink Current
 - 32-mA Output Source Current
- 3-State Outputs

CY54FCT574T . . . D PACKAGE
CY74FCT574T . . . Q OR SO PACKAGE
(TOP VIEW)



CY54FCT574T . . . L PACKAGE
(TOP VIEW)



description

The 'FCT574T devices are high-speed, low-power, octal D-type flip-flops, featuring separate D-type inputs for each flip-flop. These devices have 3-state outputs for bus-oriented applications. A buffered clock (CP) and output-enable ($\overline{OE}$) inputs are common to all flip-flops. The 'FCT574T are identical to 'FCT374T, except for a flow-through pinout to simplify board design. The eight flip-flops in the 'FCT574T store the state of their individual D inputs that meet the setup-time and hold-time requirements on the low-to-high CP transition. When $\overline{OE}$ is low, the contents of the eight flip-flops are available at the outputs. When $\overline{OE}$ is high, the outputs are in the high-impedance state. The state of $\overline{OE}$ does not affect the state of the flip-flops.

These devices are fully specified for partial-power-down applications using I_{off} . The I_{off} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.

**TEXAS
INSTRUMENTS**

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On products compliant to MIL-PRF-38535, all parameters are tested unless otherwise noted. On all other products, production processing does not necessarily include testing of all parameters.

CY54FCT574T, CY74FCT574T
8-BIT REGISTERS
WITH 3-STATE OUTPUTS

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ORDERING INFORMATION

T _A	PACKAGE†		SPEED (ns)	ORDERABLE PART NUMBER	TOP-SIDE MARKING
–40°C to 85°C	QSOP – Q	Tape and reel	5.2	CY74FCT574CTQCT	FCT574C
	SOIC – SO	Tube	5.2	CY74FCT574CTSOC	FCT574C
		Tape and reel	5.2	CY74FCT574CTSOCT	
	QSOP – Q	Tape and reel	6.5	CY74FCT574ATQCT	FCT574A
	SOIC – SO	Tube	6.5	CY74FCT574ATSOC	FCT574A
		Tape and reel	6.5	CY74FCT574ATSOCT	
	QSOP – Q	Tape and reel	10	CY74FCT574TQCT	FCT574
	SOIC – SO	Tube	10	CY74FCT574TSOC	FCT574
		Tape and reel	10	CY74FCT574TSOCT	
–55°C to 125°C	CDIP – D	Tube	6.2	CY54FCT574CTDMB	
	CDIP – D	Tube	7.2	CY54FCT574ATDMB	
	LCC – L	Tube	7.2	CY54FCT574ATLMB	

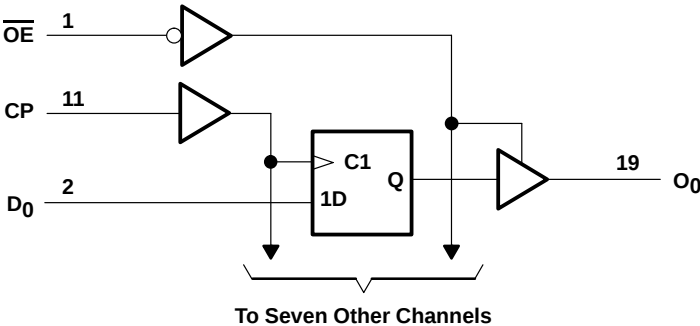
† Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

FUNCTION TABLE

INPUTS			OUTPUT O
D	CP	$\overline{OE}$	
H	↑	L	H
L	↑	L	L
X	X	H	Z

H = High logic level, L = Low logic level,
X = Don't care, Z = High-impedance state,
↑ = Low-to-high clock transition

logic diagram (positive logic)



absolute maximum ratings over operating free-air temperature range (unless otherwise noted)[†]

Supply voltage range to ground potential	–0.5 V to 7 V
DC input voltage range	–0.5 V to 7 V
DC output voltage range	–0.5 V to 7 V
DC output current (maximum sink current/pin)	120 mA
Package thermal impedance, θ_{JA} (see Note 1): Q package	68°C/W
SO package	58°C/W
Ambient temperature range with power applied, T_A	–65°C to 135°C
Storage temperature range, T_{Stg}	–65°C to 150°C

[†] Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: The package thermal impedance is calculated in accordance with JESD 51-7.

recommended operating conditions (see Note 2)

	CY54FCT574T			CY74FCT574T			UNIT
	MIN	NOM	MAX	MIN	NOM	MAX	
V_{CC} Supply voltage	4.5	5	5.5	4.75	5	5.25	V
V_{IH} High-level input voltage	2			2			V
V_{IL} Low-level input voltage			0.8			0.8	V
I_{OH} High-level output current			–12			–32	mA
I_{OL} Low-level output current			32			64	mA
T_A Operating free-air temperature	–55		125	–40		85	°C

NOTE 2: All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation.

CY54FCT574T, CY74FCT574T

8-BIT REGISTERS

WITH 3-STATE OUTPUTS

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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	CY54FCT574T			CY74FCT574T			UNIT
		MIN	TYP†	MAX	MIN	TYP†	MAX	
V_{IK}	$V_{CC} = 4.5 \text{ V}$, $I_{IN} = -18 \text{ mA}$	-0.7	-1.2					V
	$V_{CC} = 4.75 \text{ V}$, $I_{IN} = -18 \text{ mA}$				-0.7	-1.2		
V_{OH}	$V_{CC} = 4.5 \text{ V}$, $I_{OH} = -12 \text{ mA}$	2.4	3.3					V
	$V_{CC} = 4.75 \text{ V}$				2			
					2.4	3.3		
V_{OL}	$V_{CC} = 4.5 \text{ V}$, $I_{OL} = 32 \text{ mA}$	0.3	0.55					V
	$V_{CC} = 4.75 \text{ V}$, $I_{OL} = 64 \text{ mA}$				0.3	0.55		
V_{hys}	All inputs	0.2			0.2			V
I_I	$V_{CC} = 5.5 \text{ V}$, $V_{IN} = V_{CC}$			5				μA
	$V_{CC} = 5.25 \text{ V}$, $V_{IN} = V_{CC}$						5	
I_{IH}	$V_{CC} = 5.5 \text{ V}$, $V_{IN} = 2.7 \text{ V}$			± 1				μA
	$V_{CC} = 5.25 \text{ V}$, $V_{IN} = 2.7 \text{ V}$						± 1	
I_{IL}	$V_{CC} = 5.5 \text{ V}$, $V_{IN} = 0.5 \text{ V}$			± 1				μA
	$V_{CC} = 5.25 \text{ V}$, $V_{IN} = 0.5 \text{ V}$						± 1	
I_{off}	$V_{CC} = 0 \text{ V}$, $V_{OUT} = 4.5 \text{ V}$			± 1			± 1	μA
$I_{OS}^\ddagger$	$V_{CC} = 5.5 \text{ V}$, $V_{OUT} = 0 \text{ V}$	-60	-120	-225				mA
	$V_{CC} = 5.25 \text{ V}$, $V_{OUT} = 0 \text{ V}$				-60	-120	-225	
I_{OZH}	$V_{CC} = 5.5 \text{ V}$, $V_{IN} = 2.7 \text{ V}$			10				μA
	$V_{CC} = 5.25 \text{ V}$, $V_{IN} = 2.7 \text{ V}$						10	
I_{OZL}	$V_{CC} = 5.5 \text{ V}$, $V_{IN} = 0.5 \text{ V}$			-10				μA
	$V_{CC} = 5.25 \text{ V}$, $V_{IN} = 0.5 \text{ V}$						-10	
I_{CC}	$V_{CC} = 5.5 \text{ V}$, $V_{IN} \leq 0.2 \text{ V}$, $V_{IN} \geq V_{CC} - 0.2 \text{ V}$	0.1	0.2					mA
	$V_{CC} = 5.25 \text{ V}$, $V_{IN} \leq 0.2 \text{ V}$, $V_{IN} \geq V_{CC} - 0.2 \text{ V}$				0.1	0.2		
ΔI_{CC}	$V_{CC} = 5.5 \text{ V}$, $V_{IN} = 3.4 \text{ V}^\S$, $f_1 = 0$, Outputs open	0.5	2					mA
	$V_{CC} = 5.25 \text{ V}$, $V_{IN} = 3.4 \text{ V}^\S$, $f_1 = 0$, Outputs open				0.5	2		

† Typical values are at $V_{CC} = 5 \text{ V}$, $T_A = 25^\circ\text{C}$.

‡ Not more than one output should be shorted at a time. Duration of short should not exceed one second. The use of high-speed test apparatus and/or sample-and-hold techniques are preferable to minimize internal chip heating and more accurately reflect operational values. Otherwise, prolonged shorting of a high output can raise the chip temperature well above normal and cause invalid readings in other parametric tests. In any sequence of parameter tests, I_{OS} tests should be performed last.

§ Per TTL-driven input ($V_{IN} = 3.4 \text{ V}$); all other inputs at V_{CC} or GND

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted) (continued)

PARAMETER	TEST CONDITIONS			CY54FCT574T			CY74FCT574T			UNIT
				MIN	TYP†	MAX	MIN	TYP†	MAX	
I _{CCD} ††	V _{CC} = 5.5 V, Outputs open, One bit switching at 50% duty cycle, $\overline{\text{OE}}$ = GND, V _{IN} ≤ 0.2 V or V _{IN} ≥ V _{CC} – 0.2 V				0.06	0.12				mA/ MHz
	V _{CC} = 5.25 V, Outputs open, One bit switching at 50% duty cycle, $\overline{\text{OE}}$ = GND, V _{IN} ≤ 0.2 V or V _{IN} ≥ V _{CC} – 0.2 V							0.06	0.12	
I _C	V _{CC} = 5.5 V, f ₀ = 10 MHz, Outputs open, OE = GND	One bit switching at f ₁ = 5 MHz at 50% duty cycle	V _{IN} ≤ 0.2 V or V _{IN} ≥ V _{CC} – 0.2 V		0.7	1.4				mA
			V _{IN} = 3.4 V or GND		1.2	3.4				
		Eight bits switching at f ₁ = 2.5 MHz at 50% duty cycle	V _{IN} ≤ 0.2 V or V _{IN} ≥ V _{CC} – 0.2 V		1.6	3.2				
			V _{IN} = 3.4 V or GND		3.9	12.2				
	V _{CC} = 5.25 V, f ₀ = 10 MHz, Outputs open, OE = GND	One bit switching at f ₁ = 5 MHz at 50% duty cycle	V _{IN} ≤ 0.2 V or V _{IN} ≥ V _{CC} – 0.2 V					0.7	1.4	
			V _{IN} = 3.4 V or GND					1.2	3.4	
		Eight bits switching at f ₁ = 2.5 MHz at 50% duty cycle	V _{IN} ≤ 0.2 V or V _{IN} ≥ V _{CC} – 0.2 V					1.6	3.2	
			V _{IN} = 3.4 V or GND					3.9	12.2	
C _i					5	10		5	10	pF
C _O					9	12		9	12	pF

† Typical values are at $V_{CC} = 5\text{ V}$, $T_A = 25^\circ\text{C}$.

†† This parameter is derived for use in total power-supply calculations.

$I_C = I_{CC} + \Delta I_{CC} \times D_H \times N_T + I_{CCD} (f_0/2 + f_1 \times N_1)$

Where:

I_C = Total supply current

I_{CC} = Power-supply current with CMOS input levels

ΔI_{CC} = Power-supply current for a TTL high input ($V_{IN} = 3.4\text{ V}$)

D_H = Duty cycle for TTL inputs high

N_T = Number of TTL inputs at D_H

I_{CCD} = Dynamic current caused by an input transition pair (HLH or LHL)

f_0 = Clock frequency for registered devices, otherwise zero

f_1 = Input signal frequency

N_1 = Number of inputs changing at f_1

All currents are in milliamperes and all frequencies are in megahertz.

|| Values for these conditions are examples of the I_{CC} formula.

CY54FCT574T, CY74FCT574T

8-BIT REGISTERS

WITH 3-STATE OUTPUTS

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timing requirements over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1)

		CY54FCT574T		CY54FCT574AT		CY54FCT574CT		UNIT
		MIN	MAX	MIN	MAX	MIN	MAX	
t _w	Pulse duration, CP high or low	7		6		6		ns
t _{su}	Setup time, data before CP↑	2		2		2		ns
t _h	Hold time, data after CP↑	1.5		1.5		1.5		ns

timing requirements over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1)

		CY74FCT574T		CY74FCT574AT		CY74FCT574CT		UNIT
		MIN	MAX	MIN	MAX	MIN	MAX	
t _w	Pulse duration, CP high or low	7		5		5		ns
t _{su}	Setup time, data before CP↑	2		2		2		ns
t _h	Hold time, data after CP↑	1.5		1.5		1.5		ns

switching characteristics over operating free-air temperature range (see Figure 1)

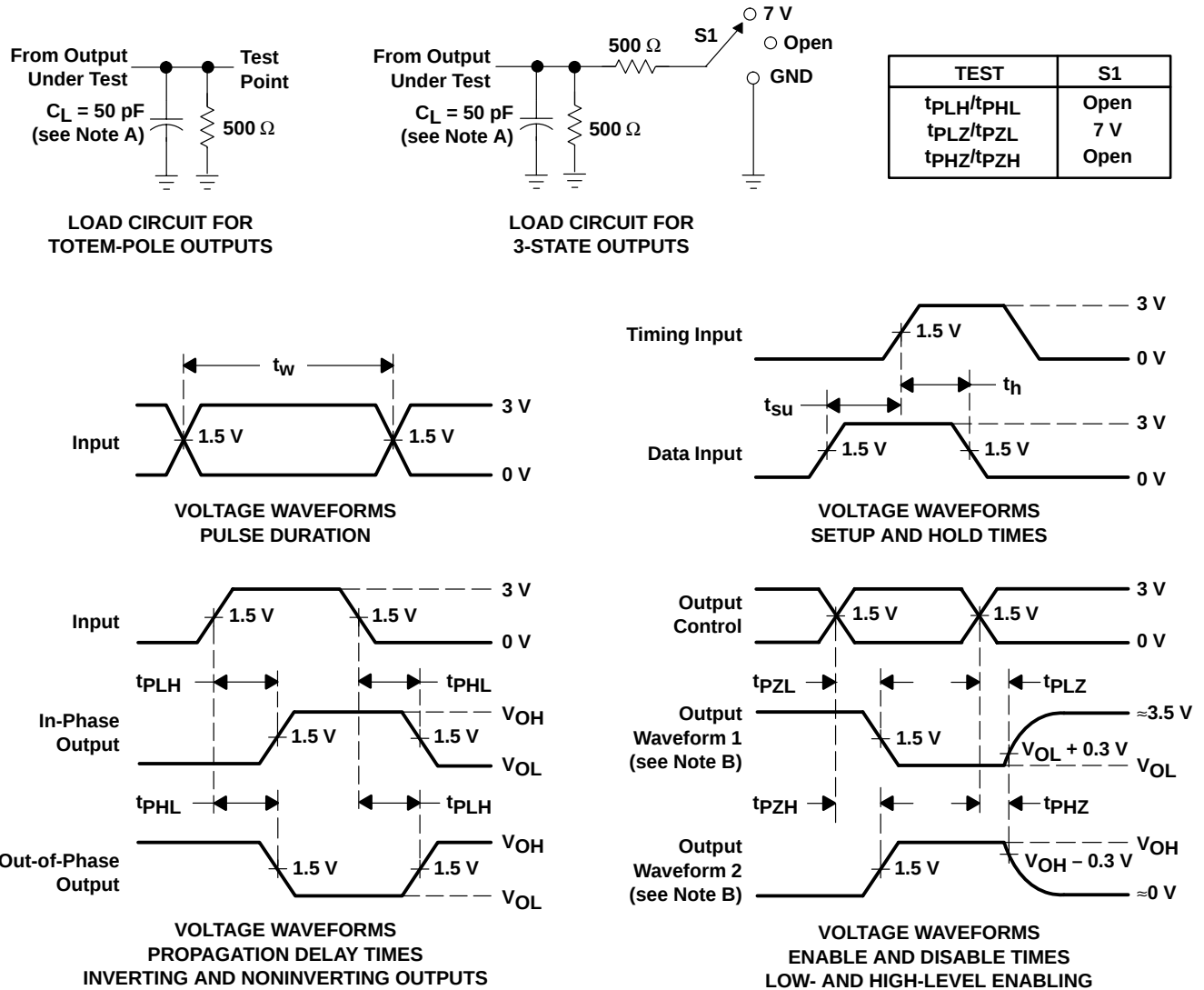
PARAMETER	FROM (INPUT)	TO (OUTPUT)	CY54FCT574T		CY54FCT574AT		CY54FCT574CT		UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	
t _{PLH}	CP	O	2	11	2	7.2	2	6.2	ns
t _{PHL}			2	11	2	7.2	2	6.2	
t _{PZH}	$\overline{OE}$	O	1.5	14	1.5	7.5	1.5	6.2	ns
t _{PZL}			1.5	14	1.5	7.5	1.5	6.2	
t _{PHZ}	$\overline{OE}$	O	1.5	8	1.5	6.5	1.5	5.7	ns
t _{PLZ}			1.5	8	1.5	6.5	1.5	5.7	

switching characteristics over operating free-air temperature range (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	CY74FCT574T		CY74FCT574AT		CY74FCT574CT		UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	
t _{PLH}	CP	O	2	10	2	6.5	2	5.2	ns
t _{PHL}			2	10	2	6.5	2	5.2	
t _{PZH}	$\overline{OE}$	O	1.5	12.5	1.5	6.5	1.5	5.5	ns
t _{PZL}			1.5	12.5	1.5	6.5	1.5	5.5	
t _{PHZ}	$\overline{OE}$	O	1.5	8	1.5	5.5	1.5	5	ns
t _{PLZ}			1.5	8	1.5	5.5	1.5	5	



PARAMETER MEASUREMENT INFORMATION



- NOTES: A. C_L includes probe and jig capacitance.
B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
C. The outputs are measured one at a time with one input transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
5962-9222203M2A	Active	Production	LCCC (FK) 20	55 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962- 9222203M2A CY54FCT 574ATLMB
5962-9222203MRA	Active	Production	CDIP (J) 20	20 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962-9222203MR A
5962-9222205MRA	Active	Production	CDIP (J) 20	20 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962-9222205MR A
CY54FCT574ATLMB	Active	Production	LCCC (FK) 20	55 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962- 9222203M2A CY54FCT 574ATLMB
CY74FCT574ATQCT	Active	Production	SSOP (DBQ) 20	2500 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	FCT574A
CY74FCT574ATQCT.B	Active	Production	SSOP (DBQ) 20	2500 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	FCT574A
CY74FCT574ATSOC	Active	Production	SOIC (DW) 20	25 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	FCT574A
CY74FCT574ATSOC.B	Active	Production	SOIC (DW) 20	25 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	FCT574A
CY74FCT574CTQCT	Active	Production	SSOP (DBQ) 20	2500 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	FCT574C
CY74FCT574CTQCT.B	Active	Production	SSOP (DBQ) 20	2500 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	FCT574C
CY74FCT574CTSOC	Active	Production	SOIC (DW) 20	25 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	FCT574C
CY74FCT574CTSOC.B	Active	Production	SOIC (DW) 20	25 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	FCT574C
CY74FCT574TQCT	Active	Production	SSOP (DBQ) 20	2500 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	FCT574
CY74FCT574TQCT.B	Active	Production	SSOP (DBQ) 20	2500 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	FCT574
CY74FCT574TSOC	Active	Production	SOIC (DW) 20	25 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	FCT574
CY74FCT574TSOC.B	Active	Production	SOIC (DW) 20	25 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	FCT574
CY74FCT574TSOCG4	Active	Production	SOIC (DW) 20	25 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	FCT574
CY74FCT574TSOCG4.B	Active	Production	SOIC (DW) 20	25 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	FCT574

⁽¹⁾ **Status:** For more details on status, see our [product life cycle](#).

⁽²⁾ **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

⁽⁴⁾ **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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TAPE AND REEL INFORMATION



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CY74FCT574ATQCT	SSOP	DBQ	20	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
CY74FCT574CTQCT	SSOP	DBQ	20	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
CY74FCT574TQCT	SSOP	DBQ	20	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CY74FCT574ATQCT	SSOP	DBQ	20	2500	353.0	353.0	32.0
CY74FCT574CTQCT	SSOP	DBQ	20	2500	353.0	353.0	32.0
CY74FCT574TQCT	SSOP	DBQ	20	2500	353.0	353.0	32.0

TUBE


*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (μm)	B (mm)
5962-9222203M2A	FK	LCCC	20	55	506.98	12.06	2030	NA
CY54FCT574ATLMB	FK	LCCC	20	55	506.98	12.06	2030	NA
CY74FCT574ATSOC	DW	SOIC	20	25	507	12.83	5080	6.6
CY74FCT574ATSOC.B	DW	SOIC	20	25	507	12.83	5080	6.6
CY74FCT574CTSOC	DW	SOIC	20	25	507	12.83	5080	6.6
CY74FCT574CTSOC.B	DW	SOIC	20	25	507	12.83	5080	6.6
CY74FCT574TSOC	DW	SOIC	20	25	507	12.83	5080	6.6
CY74FCT574TSOC.B	DW	SOIC	20	25	507	12.83	5080	6.6
CY74FCT574TSOCG4	DW	SOIC	20	25	507	12.83	5080	6.6
CY74FCT574TSOCG4.B	DW	SOIC	20	25	507	12.83	5080	6.6

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